Notice of Allowability	Application No.	Applicant(s)
	10/708,342	COMBS ET AL.
	Examiner	Art Unit
	Esaw T. Abraham	2133
The MAILING DATE of this communication apper All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	ears on the cover sheet with the co (OR REMAINS) CLOSED in this app or other appropriate communication IGHTS. This application is subject to	orrespondence address blication. If not included will be mailed in due course. THIS
1. This communication is responsive to <u>Amdt filed on 12/12/0</u>	<u>06</u> .	
2. The allowed claim(s) is/are <u>1-26</u> .		
<ul> <li>3. Acknowledgment is made of a claim for foreign priority unally and All b) Some* c) None of the:</li> <li>1. Certified copies of the priority documents have</li> <li>2. Certified copies of the priority documents have</li> <li>3. Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)).</li> <li>* Certified copies not received:</li> </ul>	e been received. e been received in Application No	
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	of this communication to file a reply of this application.	complying with the requirements
4. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give	itted. Note the attached EXAMINER' es reason(s) why the oath or declara	S AMENDMENT or NOTICE OF tion is deficient.
5. CORRECTED DRAWINGS ( as "replacement sheets") must be submitted.		
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review ( PTO-948) attached		
1)  hereto or 2)  to Paper No./Mail Date	•	
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in the O	ffice action of
Identifying indicia such as the application number (see 37 CFR 1, each sheet. Replacement sheet(s) should be labeled as such in the	.84(c)) should be written on the drawin he header according to 37 CFR 1.121(c	igs in the front (not the back) of d).
DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT I		
Attachment(s)  1. Notice of References Cited (PTO-892)	5 D Nation of Informal D	akank Aradia akan
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	<ol> <li>5. ☐ Notice of Informal Page 6. ☐ Interview Summary</li> </ol>	
	Paper No./Mail Date	e
3. Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date	7. 🗌 Examiner's Amendr	nent/Comment
4. Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. ⊠ Examiner's Stateme	nt of Reasons for Allowance
	9. ☐ Other S <b>/</b> IPI	ALBERT DECADY ENVISORY PATENT EXAMINER ECHNOLOGY CENTER 2800
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#### **DETAILED ACTION**

# Examiner's statement for reason for allowance

1. Claims **1-26** have been allowed.

The following is an examiner's statement for allowance:

# As per claim 1:

The prior art of record, Weller (U.S. PN: 6,870,388) teach a scheme is disclosed for testing an electrical device to determine a range of combinations of values of N parametric variables, i.e., a SHMOO plot, for which the device functions properly. Further, Weller teaches a method comprises defining an N-dimensional plot region comprising a plurality of operating points each corresponding to a particular combination of values of the N parametric variables. The plot region is successively subdivided into smaller sub-regions, based on determining whether the electrical device passes or fails upon testing at each operating point of a predetermined subset of operating points of the plot region or one of the smaller sub-regions, until a minimum resolution is achieved (see col. 2, lines 30-42).

The prior art of record, Clinton et al. (U.S. PN: 6,330,697) teach a pass/fail criteria of the retention time as a function of the p-well voltage for each single cell is determined typically by running a Shmoo test pattern to create a Shmoo plot. A Shmoo test monitors a set of patterns of an output of a system under test by varying, incrementally, individual parameters of the system. Information regarding each of the different root causes of the single bit faults is acquired by a typical Shmoo plot. Hence, this first step in the test method facilitates grouping the single bit failures under different

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categories and distinguishing between different types of leakage mechanisms and failures of unknown origins (see col. 5, lines 6-17).

However, the prior art taken singly or in combination fail to teach, anticipate, suggest, or render obvious Shmoo memory testing said memory array by incrementing, decrementing or both incrementing and decrementing values of a test parameter until a predetermined minimum or a predetermined maximum value of said test parameter is reached and that utilizes a requires no more than a second number of said total number of fuses for use in repairing said memory array to operate at said predetermined minimum or said predetermined maximum value of said test parameter. Consequently, claim 1 is allowed over the prior art.

Claims 2-9 and 21-23, which is/are directly or indirectly dependent/s of claim 1 are also allowable over the prior art of record.

# As per claim 10:

The prior art of record, Weller (U.S. PN: 6,870,388) teach a scheme is disclosed for testing an electrical device to determine a range of combinations of values of N parametric variables, i.e., a SHMOO plot, for which the device functions properly. Further, Weller teaches a method comprises defining an N-dimensional plot region comprising a plurality of operating points each corresponding to a particular combination of values of the N parametric variables. The plot region is successively subdivided into smaller sub-regions, based on determining whether the electrical device passes or fails upon testing at each operating point of a predetermined subset of operating points of

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the plot region or one of the smaller sub-regions, until a minimum resolution is achieved (see col. 2, lines 30-42).

The prior art of record, Clinton et al. (U.S. PN: 6,330,697) teach a pass/fail criteria of the retention time as a function of the p-well voltage for each single cell is determined typically by running a Shmoo test pattern to create a Shmoo plot. A Shmoo test monitors a set of patterns of an output of a system under test by varying, incrementally, individual parameters of the system. Information regarding each of the different root causes of the single bit faults is acquired by a typical Shmoo plot. Hence, this first step in the test method facilitates grouping the single bit failures under different categories and distinguishing between different types of leakage mechanisms and failures of unknown origins (see col. 5, lines 6-17).

However, the prior art taken singly or in combination fail to teach, anticipate, suggest, or render obvious Shmoo memory testing said memory array by incrementing, decrementing or both incrementing and decrementing values of a test parameter until a predetermined minimum or a predetermined maximum value of said test parameter is reached and that utilizes a requires no more than a second number of said total number of fuses for use in repairing said memory array to operate at said predetermined minimum or said predetermined maximum value of said test parameter, saving a first set of fuse data based on said standard memory testing of said memory array and saving a second set of fuse data based on said shmoo memory testing of said memory array and repeating steps all the above steps ((a) through (e)) until all integrated circuit

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chips to be tested have been selected. Consequently, claim 10 is allowed over the prior art.

Claims 11-20 and 24-26, which is/are directly or indirectly dependent/s of claim 10 are also allowable over the prior art of record.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

### Conclusion

2. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Weller (U.S. PN: 6,870,388)

Clinton et al. (U.S. PN: 6,330,697)

3. Any inquiry concerning this communication or earlier communication from the examiner should be directed to Esaw Abraham whose telephone number is (571) 272-3812. The examiner can normally be reached on M-F 8-5.

If attempts to reach the examiner by telephone are successful, the examiner's supervisor, Albert DeCady can be reached on (571) 272-3819. The fax phone numbers for the organization where this application or proceeding is assigned (571) 273-8300.

Information regarding the status of an Application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published

applications may be obtained from either Private PAIR or PUBLIC PAIR. Status information for unpublished applications is available through Private Pair only. For more information about the PAIR system, see <a href="http://pair-direct.uspto.gov">http://pair-direct.uspto.gov</a>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Esaw Abraham

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SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2100